



Date: Dec 02, 2016

Advertisement for JRF Position

Applications are invited from motivated and eligible candidates for the position of Junior Research Fellow (JRF) in a ISRO funded Research Project titled "*Design, modeling and Simulation of GaAs based III-V semiconductor multi junction solar structures for space applications*".

Eligibility

Essential Qualification:

- (i) M.Tech./M.E/MS degree in Electronics and Communication Engineering or in equivalent streams. OR
- (ii) B.Tech/BE in degree Electronics and Communication Engineering or in equivalent streams with a valid Gate/NET score.

Preference will be given to candidates having experience/specialization in device design, mathematical modeling of devices, Photovoltaics, semiconductor physics.

Stipend

The amount of JRF fellowship will be as per ISRO norms and it is Rs. 25,000 per month. In addition, the candidate will be provided with 10% HRA.

Duration

Initial appointment will be for one year, which is extendable up to 3 years solely based on performance.

Age Limit: The upper age limit for candidate shall be 28 years.

Travel:

The candidate may need to travel to ISRO Bengaluru during the progress of the project.

How to Apply

Interested candidates are requested to submit a detailed CV (in pdf format) with Subject line: Application for JRF to Dr. K. Siva Prasad, via e- mail siva.k@iiits.in latest by **07 January 2017**. Complete information with regard to GATE/NET score such as: year of passing, discipline, score, marks, All India Rank should be mentioned in the CV. Incomplete applications will be rejected.

No TA/DA will be paid for attending the interview.

Only shortlisted candidates will be called for interview. Selected candidate will be intimated through email.